



GRAPHENE FLAGSHIP

Full relativistic calculations on 2D materials

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Workshop on correlations, criticality, and coherence in quantum systems
Évora 6-10 October 2014



Universidade do Minho

Summary

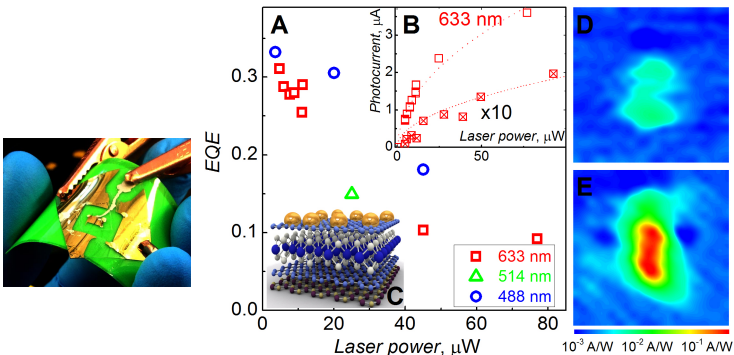
- Introduction and motivation
- Relativistic calculations
- The Transition Metal Dichalcogenides
- Optical conductivity: band nesting
- Conclusions and future developments



Photoelectric devices with TMDC

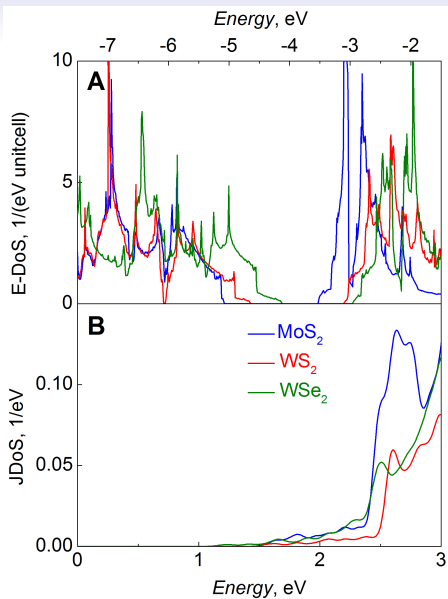
Heterostructure of 2D materials

BN / Gr / TMDC / Gr / BN TMDC= MoS₂, WS₂, WSe₂



L. Britnell *et al.*, Science **340** (2013) 1311

- External quantum efficiency $\sim 30\%$ (A)
- Larger quantum efficiency for lower intensities (B)
- Photocurrent increases 10x with gold nanoparticles (D, E)



Full Relativistic Calculations

Basically, use Dirac KS equation instead of Schrödinger equation.

$$\{-i\hbar c \boldsymbol{\alpha} \cdot \boldsymbol{\nabla} + (\beta - 1) mc^2 + v_s(\mathbf{r}) + \mu_B \beta \boldsymbol{\Sigma} \cdot \mathbf{B}_s(\mathbf{r})\} \phi_i(\mathbf{r}) = \varepsilon_i \phi_i(\mathbf{r})$$

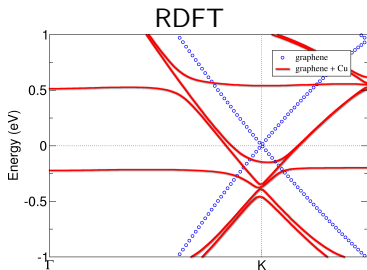
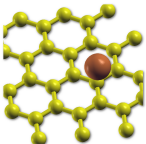
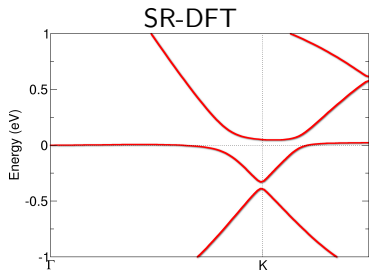
with the 4-component spinors:

$$\phi_i(\mathbf{r}) = \begin{bmatrix} \phi_i^0(\mathbf{r}) \\ \phi_i^1(\mathbf{r}) \\ \phi_i^2(\mathbf{r}) \\ \phi_i^3(\mathbf{r}) \end{bmatrix}$$

Atomic energy levels: Non-Relativistic, Scalar-Relativistic, Full-Relativistic

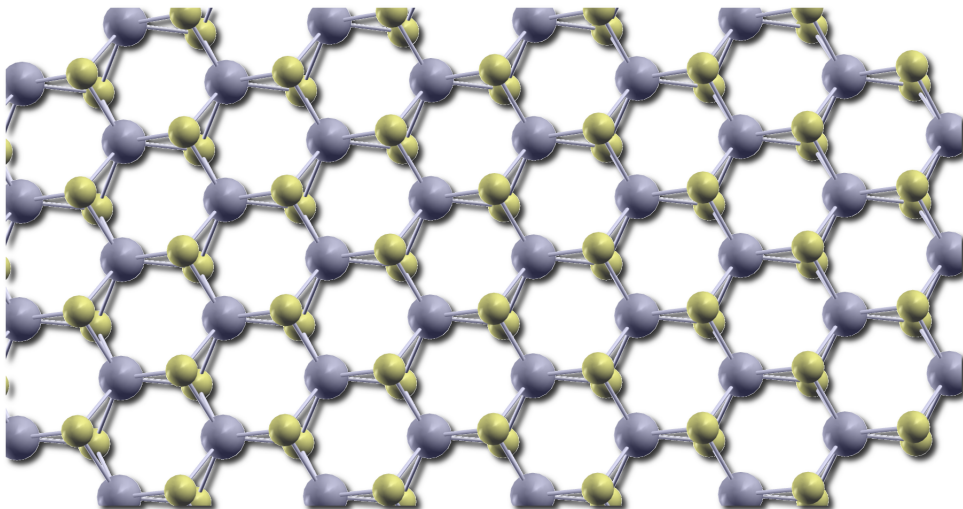
	nl	NR-DFT (eV)	SR-DFT (eV)	j	RDFT (eV)
C	2p	-5.2887	-5.2855	0.5	-5.2876
C	2p			1.5	-5.2789
Cu	3d	-5.2137	-5.0378	1.5	-5.2024
Cu	3d			2.5	-4.9324
Mo	4d	-3.9908	-3.7529	1.5	-3.8112
Mo	4d			2.5	-3.6085
W	5d	-5.8050	-4.4802	1.5	-4.6458
W	5d			2.5	-3.9348

Copper on graphene



The differences are clear: even for a *light* system there is a notable Rashba-Dresselhaus effect.

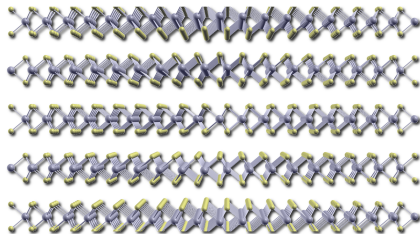
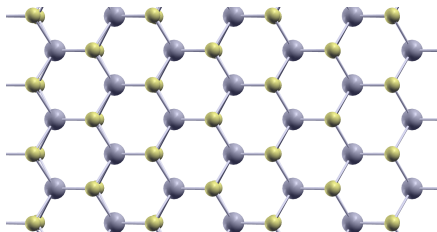
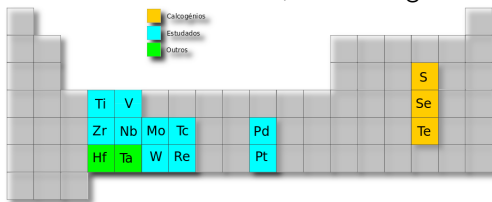
Transition Metal Dichalcogenides (TMDC)



Transition Metal Dichalcogenides (TMDC)

Materials like: MX_2

M=transition metal; X=chalcogen



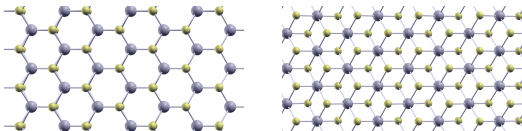
Easy to exfoliate

Transition Metal Dichalcogenides

Hexagonal structures

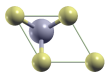
Materials of type: MX_2

$\text{M} = \text{Ti, V, Zr, Nb, Mo, Tc, Pd, Hf, Ta, W, Re, Pt}; \quad \text{X} = \text{S, Se, Te}$



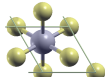
Two types of structures:

Trigonal prismatic



No inversion

Octaedic



Has inversion

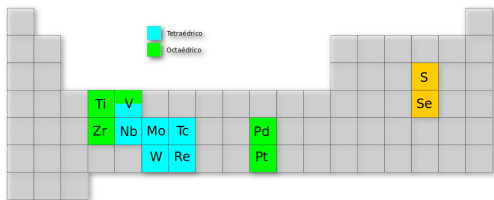
(side)

(top)

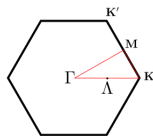
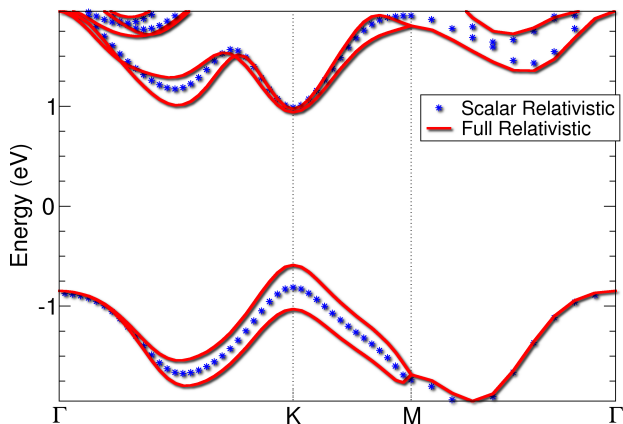
Trigonal prismatic (T-) or octahedral (O-)?

Which is the preferred structure? (Lattice parameters (\AA) and relative energy $\Delta E = E_O - E_T$ (eV))

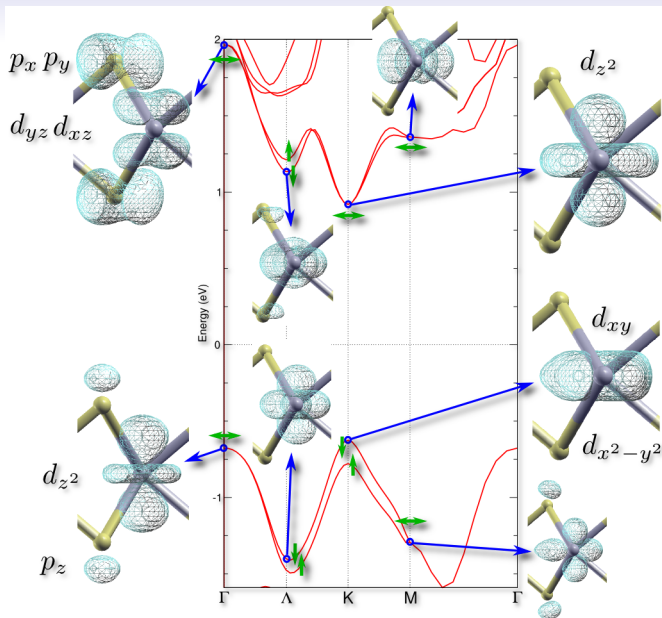
M	O-MS ₂	T-MS ₂	ΔE	O-MSe ₂	T-MSe ₂	ΔE
Ti	3.48	3.41	-0.40	3.40	3.38	-0.33
V	3.25	3.23	0.03	3.34	3.35	-0.01
Zr	3.74	3.64	-0.50	3.60	3.56	-0.39
Nb	3.42	3.40	0.12	3.52	3.52	0.10
Mo	3.22	3.23	0.81	3.33	3.37	0.68
Tc	3.13	3.32	0.35	3.24	3.48	0.31
Pd	3.61	-	-	3.76	-	-
W	3.23	3.21	0.86	3.84	3.76	0.74
Re	3.15	3.33	0.24	3.23	3.48	0.26
Pt	3.61	3.54	-1.67	3.78	3.70	-1.28



Description of TMDC



Band diagram of WS_2 , NR-DFT e RDFT calculations. On the right, the high symmetry points in the reciprocal space are shown.



MoS₂ monolayer,
trigonal prismatic
structure.

Wavefunctions in
the signaled
points of the band
diagram (blue
arrows).

Green arrows
show the nature
of the spin.

Electronic and optical properties

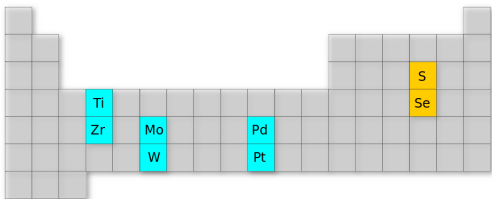
Among the TMDC single layers, we will take a look at the ones that are **semiconductors**.

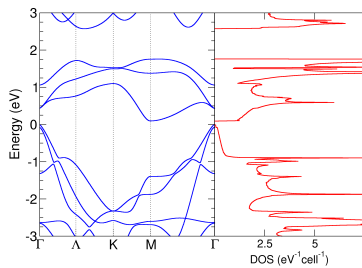
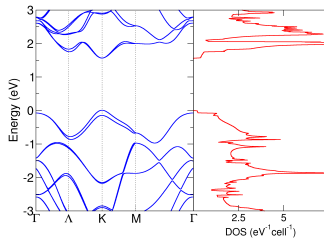
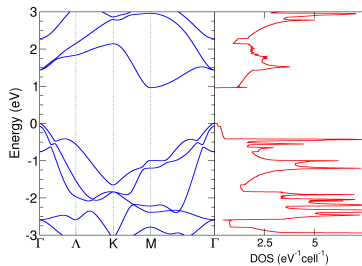
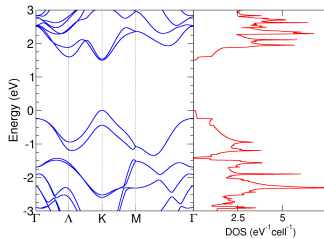
These are, in trigonal form:

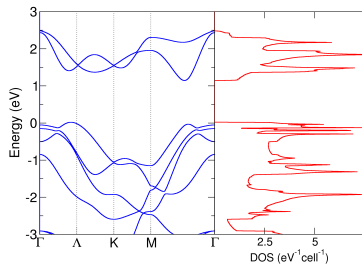
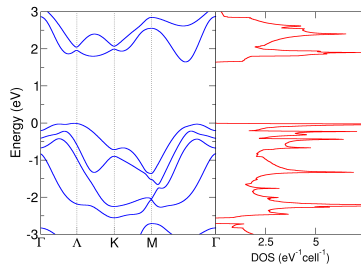
TiS_2 , ZrS_2 , MoS_2 , WS_2 , TiSe_2 , ZrSe_2 , MoSe_2 , WSe_2 .

And in octahedral form:

TiS_2 , ZrS_2 , PdS_2 , PtS_2 , ZrSe_2 , PdSe_2 , PtSe_2 .



O-TiS₂T-MoS₂O-ZrS₂T-WS₂

O-PdS₂O-PtS₂

Optical conductivity: *band nesting*

Critical points: $\nabla_k (E_c - E_v) = 0$.

$$\nabla_k E_c = \nabla_k E_v = 0 \Rightarrow \begin{cases} \text{maximum} \\ \text{minimum} \\ \text{saddle point} \end{cases}$$

on each band. These are the van Hove (VHS) singularities; give origin to peaks in the DOS. This, in general, can only occur in high symmetry points.

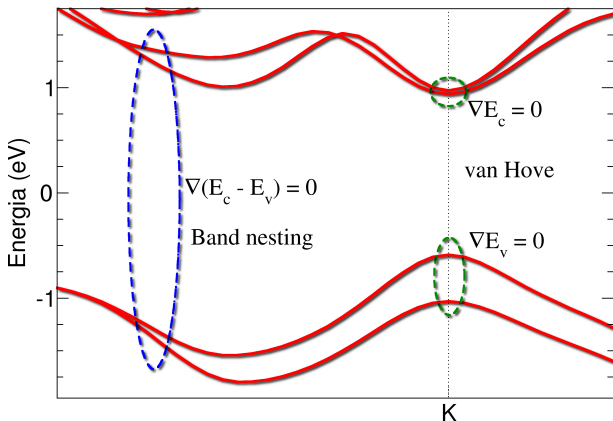
$$\nabla_k (E_c - E_v) = 0, \text{ com } |\nabla_k E_c| \approx |\nabla_k E_v| > 0, \equiv \textit{band nesting}$$

Phys. Rev. B 88 (2013) 115205

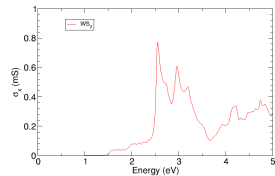
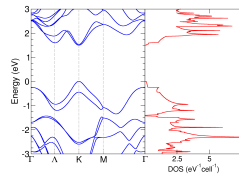
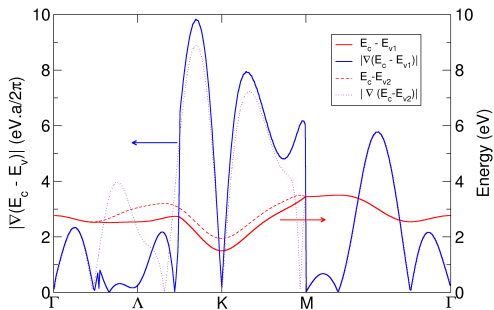
Can happen anywhere in the BZ.

Band nesting \times van Hove singularities

Critical points: $\nabla_k (E_c - E_v) = 0$

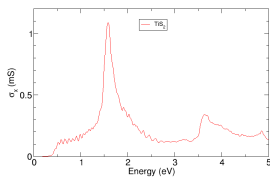
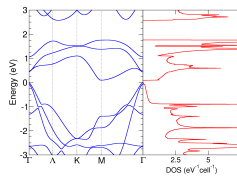
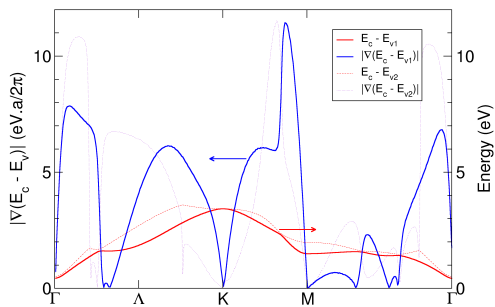


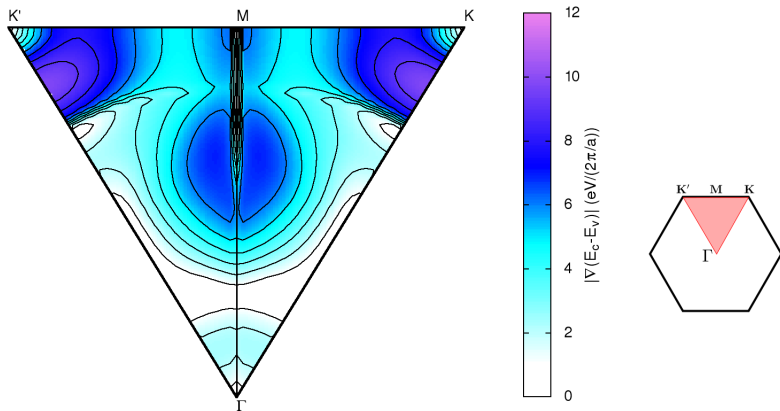
Charges move in opposite directions!

T-WS₂

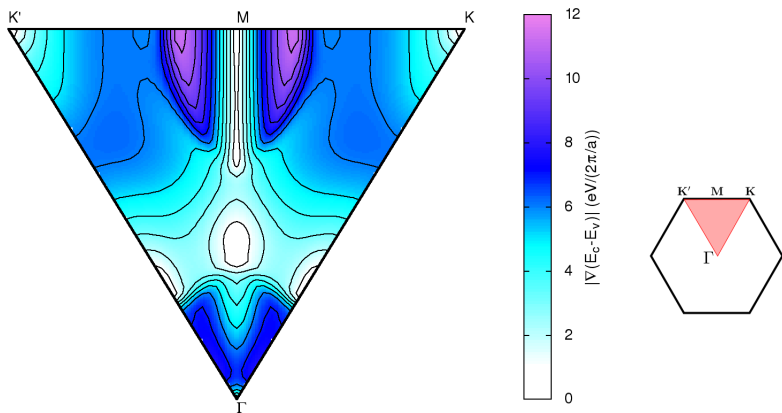
Criterion: $|\nabla_k(E_c - E_v)| < 1 \text{ eV.a}/2\pi.$

a is the lattice constant.

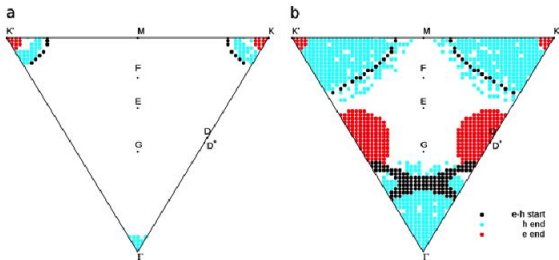
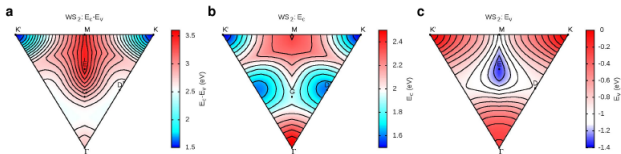
O-TiS₂



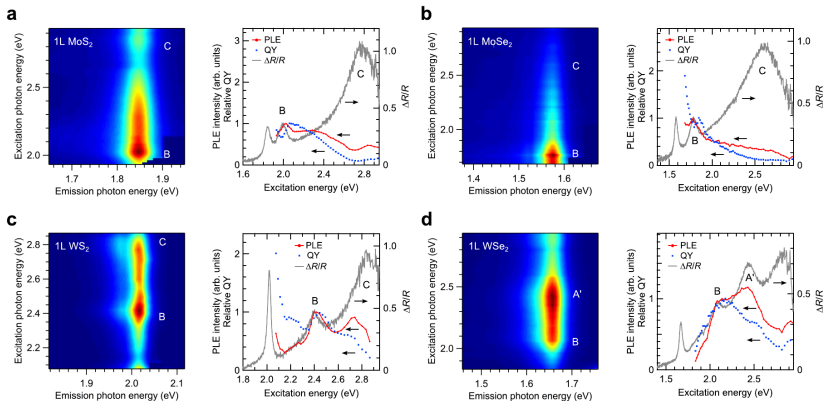
Map in BZ of $|\nabla_k(E_c - E_v)|$ for T-WS₂. a is the lattice constant.



Monte-Carlo



Experimental



PLE intensity map, PLE spectra, relative quantum yield (QE) of emission for band gap emission, and differential reflectance spectra.

Conclusions and future developments

- Bi-dimensional materials will continue to surprise us with interesting properties;
- It is necessary to be alert to eventual relativistic phenomena;
- A simple criterion to find high optical absorption in materials has been established, for less obvious regions in the reciprocal space.

Collaborations / Sponsors

From NUS

Graphene Research Centre



António H. Castro Neto



Alexandra Carvalho



Goki Eda group (experiment)

From Manchester



Kostya Novoselov group
(experiment)



FCT Fundação para a Ciência e a Tecnologia
MINISTÉRIO DA CIÊNCIA, TECNOLOGIA E ENSINO SUPERIOR Portugal

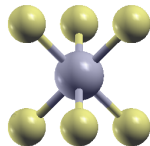
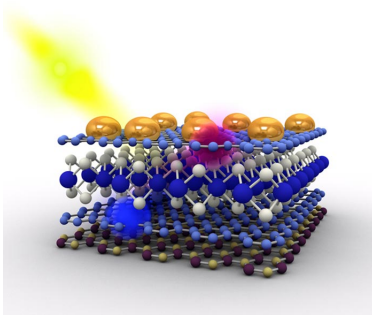
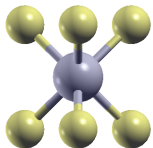


Governo da República Portuguesa

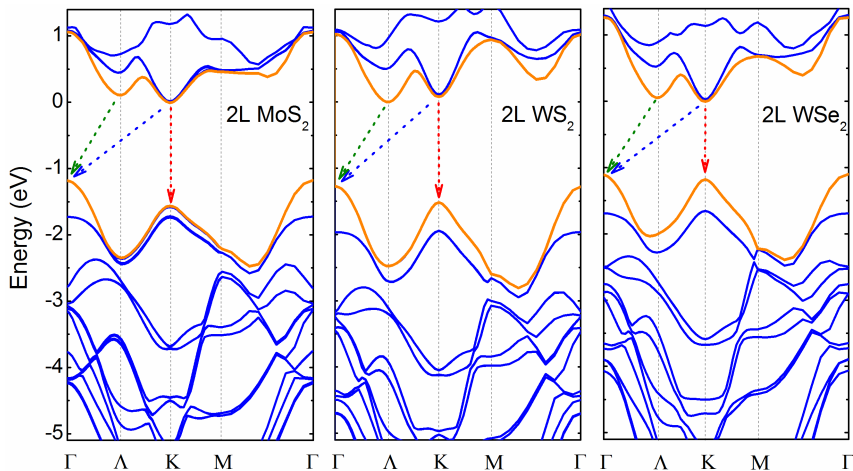
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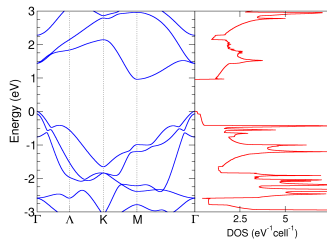
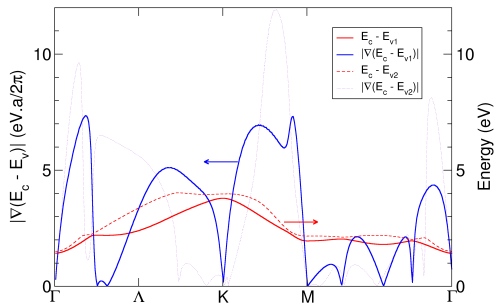


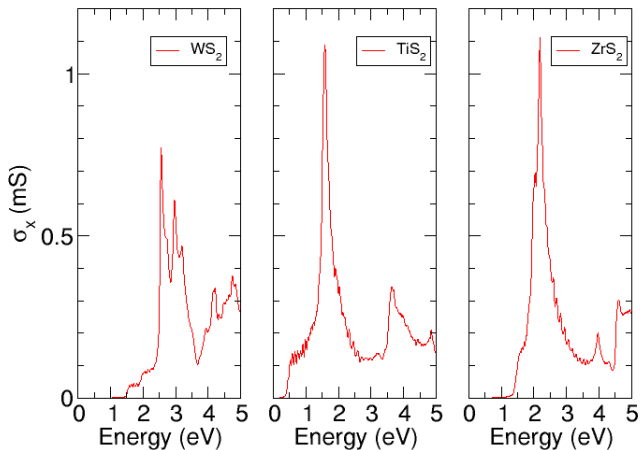
Thank you!



Bi-layers: observed transitions



O-ZrS₂



Real part of the optical conductivity of WS₂, TiS₂, e ZrS₂ single layers.